

## NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE2301B uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

### **General Features**

•  $V_{DS} = -20V, I_{D} = -2.6A$ 

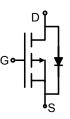
 $R_{DS(ON)}$  < 160m $\Omega$  @  $V_{GS}$ =-2.5V

 $R_{DS(ON)} < 120 m\Omega$  @  $V_{GS}$ =-4.5V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

## **Application**

- PWM applications
- Load switch



Schematic diagram



Marking and pin assignment



SOT-23 top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301B	NCE2301B	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	-20	V	
Gate-Source Voltage	V <sub>GS</sub>	±12	V	
Drain Current-Continuous	I <sub>D</sub>	-2.6	Α	
Drain Current -Pulsed (Note 1)	I <sub>DM</sub>	-13	Α	
Maximum Power Dissipation	P <sub>D</sub>	0.9	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}$	

### **Thermal Characteristic**

## **Electrical Characteristics (T<sub>A</sub>=25℃ unless otherwise noted)**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-20		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	-1	μA



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# NCE2301B

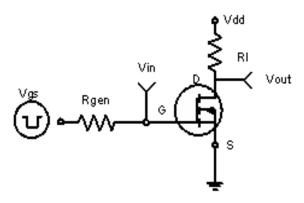
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
Drain Course On Ctata Basistana	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2 A	-	78	120	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.8A	-	102	160	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-1A	6	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	\/ - 40\/\/ -0\/	-	325	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =-10V,V <sub>GS</sub> =0V,	-	63	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	37	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	11	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-10V, $R_L$ =5 $\Omega$	-	5.5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5 $V$ , $R_{GEN}$ =3 $\Omega$	-	22	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	8	-	nS
Total Gate Charge	Qg	\/ 40\/ L 0A	-	3.2	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-10V,I <sub>D</sub> =-2A,	-	0.6	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-4.5V	-	0.9	-	nC
Drain-Source Diode Characteristics	,		•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =2A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-2.6	Α

## Notes:

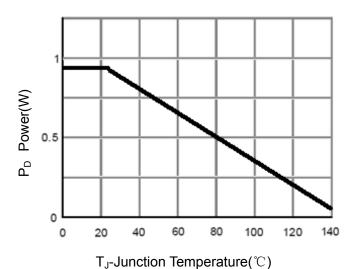
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



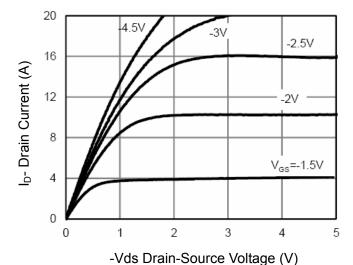
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

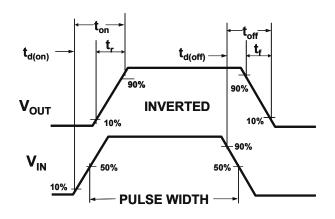
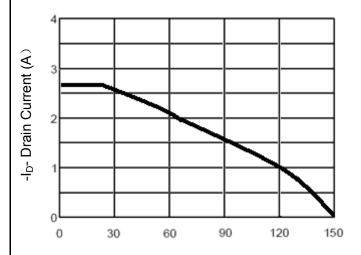


Figure 2:Switching Waveforms



T<sub>J</sub>-Junction Temperature(°C)

Figure 4 Drain Current

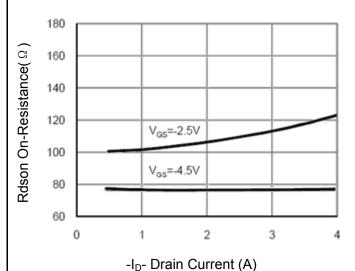
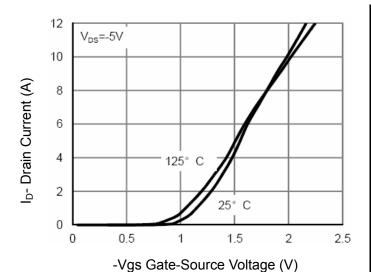


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 

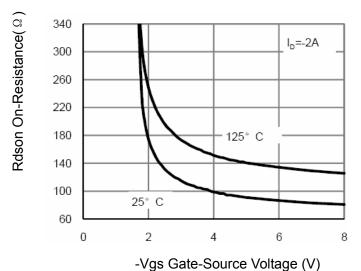


Figure 9 Rdson vs Vgs

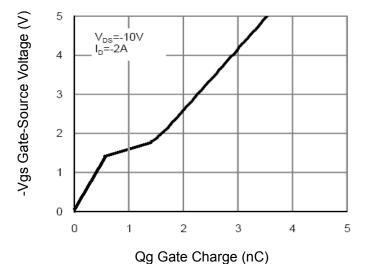


Figure 11 Gate Charge

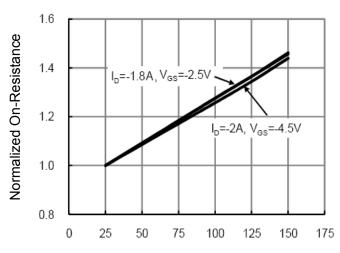


Figure 8 Drain-Source On-Resistance

 $T_J$ -Junction Temperature( $^{\circ}$ C)

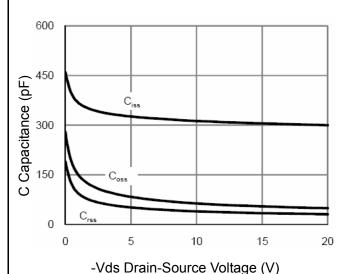


Figure 10 Capacitance vs Vds

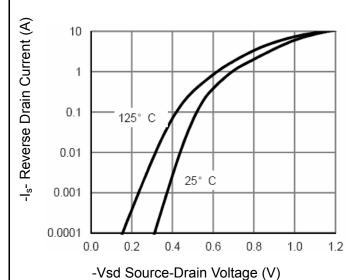


Figure 12 Source- Drain Diode Forward



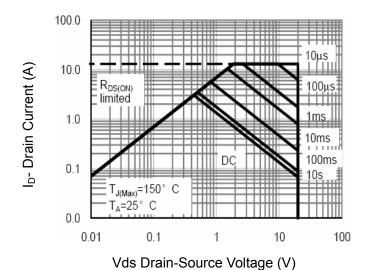
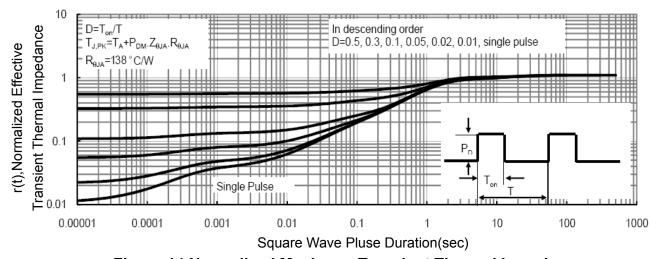


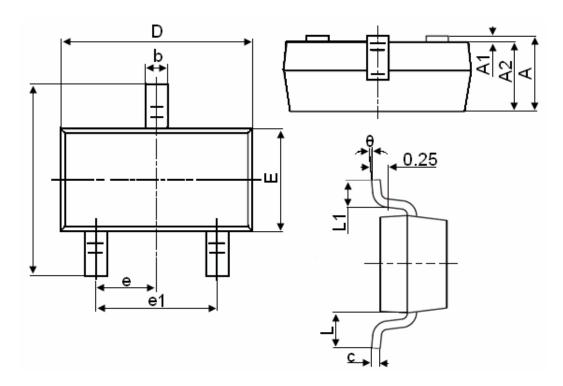
Figure 13 Safe Operation Area



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



## **SOT-23 Package Information**



Symbol	Dimensions in Millimeters			
Syllibol	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



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## **NCE2301B**

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